Transformative Evolution of Organolead Triiodide Perovskite Thin Films from Strong Room-Temperature Solid–Gas Interaction between HPbl₃-CH₃NH₂ Precursor Pair

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Supporting Information

ABSTRACT: We demonstrate the feasibility of a nonsalt-based precursor pair—inorganic HPbl₃ solid and organic CH₃NH₂ gas—for the deposition of uniform CH₃NH₃PbI₃ perovskite thin films. The strong room-temperature solid–gas interaction between HPbl₃ and CH₃NH₂ induces transformative evolution of ultrasmooth, full-coverage perovskite thin films at a rapid rate (in seconds) from nominally processed rough, partial-coverage HPbl₃ thin films. The chemical origin of this behavior is elucidated via in situ experiments. Perovskite solar cells, fabricated using MAPbI₃ thin films thus deposited, deliver power conversion efficiencies up to 18.2%, attesting to the high quality of the perovskite thin films deposited using this transformative process.

Since the use of methylammonium lead triiodide (CH₃NH₃PbI₃ or MAPbI₃) perovskite as the light absorber material in solar cells by Kojima et al. in 2009, the power conversion efficiency (PCE) of perovskite solar cells (PSCs) has shot up rapidly within a short period of time. The rapid advances in PSCs are enabled by enhanced control over the formation of uniform MAPbI₃ absorber films via myriad processing methods. In particular, the sequential deposition method, where the formation of the MAPbI₃ occurs by reaction between the organic precursor with the predeposited inorganic precursor counterpart, has gained wide popularity. An unprecedented amount of effort has been devoted to developing this method, and its variations, for improving the quality of resultant MAPbI₃ films, but it has yielded mixed results. All this effort invariably involves precursor pairs consisting of an inorganic lead salt and an organic methylammonium salt, with the PbI₂-MAI pair being the most typical example. The reaction, PbI₂ + MAI → MAPbI₃, involves the formation of new Pb–I bonds toward the construction of the 3D perovskite structure, and it is regarded as a neutralization reaction of the electrophile (acid) PbI₂ with the nucleophile (base) MAI, but the acidity/basicity of these two salts is low. Thus, the mutual interaction between salts-based precursors is expected to be relatively weak. Also, the insertion kinetics of MAI species into 2D layered PbI₂ octahedral arrays of PbI₂, especially in its bulk form, is sluggish considering the long diffusion pathways and the reconstructive nature of the 2D → 3D structural transformation. Furthermore, the use of certain solvents (e.g., isopropanol) usually associated with this process has a detrimental effect on the morphology of the final perovskite films.

These considerations provide the motivation for discovering new precursor pairs that (i) exhibit strong mutual interaction, (ii) enhance perovskite-crystallization kinetics, and (iii) avoid the use of liquid solvents. In this context, inspection of the stoichiometry of MAPbI₃ suggests a new possible precursor pair consisting of hydrogen lead triiodide (HPbl₃) as the inorganic component and methylamine gas (CH₃NH₂) as the organic component. The synthesis of HPbl₃ was first reported by Zhao et al., but in this study we have used an antisolvent-crystallization method (described in the Supporting Information (SI)) based on stoichiometric PbI₂/HI precursors for obtaining excellent quality HPbl₃ crystals. Pawley fitting of the X-ray diffraction (XRD) pattern of these HPbl₃ crystals (powder) in Figure 1A shows an orthorhombic (space group P6₃mc) structure with lattice parameters a = b = 8.765(1) Å, c = 18.772(2) Å. This is further supported by the high-resolution transmission electron microscopy (HR-TEM) image of HPbl₃ solution deposited onto a TEM grid directly, shown in Figure 1A (inset). The lattice fringes with interplanar distance of 0.62 nm can be assigned to (110) planes of the orthorhombic HPbl₃ crystal. (Note: The H atom that is intercalated into the orthorhombic crystal is not considered for the symmetry here; more detailed characterization is underway for further elucidation of the complete crystal structure of HPbl₃.) The other precursor in the new pair, CH₃NH₂ has a boiling point of −6.8 °C and is a gas at room temperature. Thus, to demonstrate the feasibility of MAPbI₃ perovskite formation using this new precursor pair, the solid HPbl₃ powder is simply exposed to the CH₃NH₂ gas and is then removed from the gas. The light-yellow HPbl₃ powder is converted into a black phase when this process is complete. The Pawley fit of the XRD pattern (Figure 1B) of the resultant black phase confirms tetragonal MAPbI₃ perovskite (space group I4/mcm; lattice parameters a = b = 8.873(1) Å, c = 12.662(1) Å). The HR-TEM images in Figure 1B (inset) shows lattice fringes with interplanar distance of 0.44 nm, corresponding to (112) or (020) planes in MAPbI₃ perovskite. These results...
clearly show the conversion of HPbI₃ crystalline phase to MAPbI₃ perovskite with CH₃NH₃-gas treatment.

The possible crystallographic conversion mechanism from HPbI₃ to MAPbI₃ is shown schematically in Figure 1C. The pseudo-3D crystal structure of HPbI₃ consists of arrays of 1D face-shared PbI₆ octahedra with intercalated protons (H⁺) for charge balance. Upon exposure to CH₃NH₂ gas, the CH₃NH₂ molecules readily react with H⁺ via the reaction, CH₃NH₂ + H⁺ → CH₃NH₃⁺, with enhanced affinity toward the 1D face-shared PbI₆ octahedra chains. Once the adjacent 1D PbI₆ octahedra transitions into 3D perovskite structure with corner-shared PbI₆ octahedra. It is obvious that H⁺ plays an important role in the stoichiometric formation of MAPbI₃ perovskite, which is further supported by the fact that stable perovskite phase could not be formed using a KI–PbI₂ system instead of HPbI₃ (see Figure S1).

The new HPbI₃–CH₃NH₂ precursor pair for the formation of MAPbI₃ perovskite has the following unique characteristics, as compared with the conventional PbI₂–MAI precursor pair. First, the perovskite formation is driven by the strong acid–base interaction between H⁺ with the CH₃NH₂. Second, the gaseous nature of CH₃NH₂ allows highest contact area with the HPbI₃ solid precursor and facilitates the reaction, precluding the need for solvents or thermally induced ionization that are typically needed for making the MAI phase more reactive in salt-based precursor pairs. Finally, in the HPbI₃ structure, Pb–I bonds are fully formed, whereas the intercalation reaction of PbI₂ with MAI entails the formation of new Pb–I bonds in the conventional precursor pair case. Thus, a near-topotactic conversion of the HPbI₃ crystal structure to MAPbI₃ perovskite occurs, as illustrated in Figure 1C.

In order to gain insight into the details of the HPbI₃-to-MAPbI₃ phase conversion process and the associated morphological evolution, a combination of in situ optical and photoluminescence (PL) microscopies is used. Figure 2A shows the evolution of a rod-like HPbI₃ crystal (typical morphology for solution-grown HPbI₃) into a MAPbI₃ particle using optical microscopy. Upon exposure to CH₃NH₂ gas at room temperature for 5 min, the HPbI₃ crystal gradually turns into a liquid phase. Upon removal of the CH₃NH₂ gas at room temperature, the liquid drop gradually crystallizes into MAPbI₃ perovskite (30 min), as confirmed by XRD and PL microscopy (Figure 1B). Since HPbI₃, the intermediate liquid phase, and MAPbI₃ perovskite have obviously distinct PL responses, in situ PL microscopy is an ideal tool for following the evolution of these phases during the reaction in thin films. Here, HPbI₃ dissolved in DMF solvent is spin-coated (60 wt %, 6000 rpm, 20 s) onto a glass substrate and heated (150 °C, 2 min) to form a HPbI₃ thin film. In Figure 2B (left), which is an optical image with superimposed PL map, the initial as-synthesized HPbI₃ film shows highly heterogeneous morphology and incomplete coverage, and as expected no PL emission is observed within the detection limit. Upon exposure to CH₃NH₂ gas at room temperature for 2 s (Figure 2B center), the HPbI₃ grains have disappeared showing null optical contrast and PL signal that of a nonluminescent liquid. Upon degassing for 2 s (Figure 2B right), a strongly luminescent MAPbI₃ film readily appears with uniform coverage on the substrate. The MAPbI₃ perovskite phase in that film is confirmed by XRD (Figure S2), which shows strong absorption in the UV–vis spectrum (Figure S3). The intermediate liquid phase is clearly the result of the strong interaction between HPbI₃ solid and CH₃NH₂ gas, and its amorphous structure and transparent nature are revealed by XRD and UV–vis in Figure S4, respectively. Through careful weighing of the initial HPbI₃ powder and the liquid (Figure S5 A), it is determined that the liquid contains ∼4.5 CH₃NH₂ per HPbI₃. From stoichiometry considerations, this is reminiscent of the MAPbI₃-xCH₃NH₂ (x ~ 3.5) intermediate liquid phase that forms when MAPbI₃ solid uptakes CH₃NH₂ gas molecules via...
“metastable” interaction in our previous report.\textsuperscript{11} It is observed (Figure S6) that such CH\textsubscript{3}NH\textsubscript{2}-uptake behavior does not occur when the MAPbI\textsubscript{3} is heated to an elevated temperature (150 °C), indicating that “metastable” interaction observed at room temperature is unfavorable at 150 °C. Therefore, a set of control in situ optical and PL microscopy experiments were conducted at 150 °C to gain insight into the origin of the ∼4.5 CH\textsubscript{3}NH\textsubscript{2} uptake per HPbI\textsubscript{3} at room temperature.

Figure 2C shows the morphological evolution of a HPbI\textsubscript{3} crystal upon treatment of CH\textsubscript{3}NH\textsubscript{2} at 150 °C using optical microscopy. It can be seen the HPbI\textsubscript{3} crystal darkens progressively upon exposure to CH\textsubscript{3}NH\textsubscript{2} (Figure 2C), but even after 30 min exposure there is no formation of liquid or change in the morphology of the crystal. The corresponding results from the HPbI\textsubscript{3} thin film are presented in Figure 2D. Upon exposure to CH\textsubscript{3}NH\textsubscript{2} gas at 150 °C for 5 s (Figure 2D, center), some PL signal is observed. After 20 s (Figure 2D, right) all the HPbI\textsubscript{3} grains in the film have transformed to MAPbI\textsubscript{3} without significant change in the film morphology; the PL map mirrors the heterogeneity and the partial coverage of the initial HPbI\textsubscript{3} thin film. The XRD pattern (Figure S7) and UV–vis absorption spectrum (Figure S3) of the resultant film confirm MAPbI\textsubscript{3} perovskite phase.\textsuperscript{7} The striking contrast between the homogeneous, full-coverage morphology of the final MAPbI\textsubscript{3} thin films obtained by room-temperature CH\textsubscript{3}NH\textsubscript{2}-gas treatment (Figure 2B, right) and the heterogeneous, partial-coverage morphology obtained at 150 °C (Figure 2D, right) indicates that the MAPbI\textsubscript{3} perovskite reconstruction via the MAPbI\textsubscript{3}–CH\textsubscript{3}NH\textsubscript{2} “metastable” interaction does not occur in the latter. This is also supported by the distinct crystallographic characteristics (texture, etc.) of the two MAPbI\textsubscript{3} films as revealed by the XRD patterns (Figures S2 and S7). Thus, at elevated temperature, only 1 CH\textsubscript{3}NH\textsubscript{2} is uptaken per HPbI\textsubscript{3}\textsubscript{y}, resulting in the formation of a stoichiometric MAPbI\textsubscript{3} perovskite via stable ionic/covalent interaction (eqn 1). This is further supported by careful weighing experiments (Figure S5B).

Therefore, the 4.5 CH\textsubscript{3}NH\textsubscript{2} uptaken by HPbI\textsubscript{3} at the CH\textsubscript{3}NH\textsubscript{2}-exposure stage at room temperature includes two parts: 1 CH\textsubscript{3}NH\textsubscript{2} that is responsible for the stoichiometric formation of MAPbI\textsubscript{3} nuclei and 3.5 CH\textsubscript{3}NH\textsubscript{2} that rapidly “melts” the as-nucleated MAPbI\textsubscript{3} perovskite. As the CH\textsubscript{3}NH\textsubscript{2}-uptake behavior occurs at the molecular scale, these two parts appear to occur simultaneously (Figure 2A,B), resulting in the formation of intermediate MAPbI\textsubscript{3}–3.5CH\textsubscript{3}NH\textsubscript{2} liquid phase, where the excess 3.5 CH\textsubscript{3}NH\textsubscript{2} is subsequently released upon degassing due to the “metastable” nature of the original 3.5 CH\textsubscript{3}NH\textsubscript{2} uptake (eqn 2).

\begin{equation}
\text{HPbI}_3(s) + \text{CH}_3\text{NH}_2(g) \rightarrow \text{MAPbI}_3(s) \\
(1)
\end{equation}

\begin{equation}
\text{HPbI}_3(s) + (1 + x)\text{CH}_3\text{NH}_2(g) \rightarrow \text{MAPbI}_3\cdot x\text{CH}_3\text{NH}_2(l) \\
\rightarrow \text{MAPbI}_3(s) + x\text{CH}_3\text{NH}_2(g) \\
(2)
\end{equation}

The room-temperature interaction between the nanoscale film of HPbI\textsubscript{3} and the CH\textsubscript{3}NH\textsubscript{2} gas occurs within seconds (eqn 2), which opens up a remarkable opportunity to form ultrasmooth MAPbI\textsubscript{3} perovskite thin films using this facile chemical route, as shown schematically in Figure 3. First, upon simple exposure to CH\textsubscript{3}NH\textsubscript{2} gas, the nominally solution-deposited HPbI\textsubscript{3} film (rough, partial coverage) uptakes (1 + x) CH\textsubscript{3}NH\textsubscript{2}, converting it into a smooth “liquid” film of MAPbI\textsubscript{3}·xCH\textsubscript{3}NH\textsubscript{2} that spreads over the whole substrate. This step is the result of the “shape-preserved” perovskite formation with 1 CH\textsubscript{3}NH\textsubscript{2} uptake, followed rapidly by perovskite “melting” process with excess x CH\textsubscript{3}NH\textsubscript{2} uptake (indicated by dashed arrows in Figure 3). Upon the removal of CH\textsubscript{3}NH\textsubscript{2} atmosphere, supersaturation occurs rapidly with the release of x CH\textsubscript{3}NH\textsubscript{2}, resulting in the crystallization of the ultrasmooth stoichiometric MAPbI\textsubscript{3} perovskite thin film.\textsuperscript{12}

The scanning electron microscope (SEM) images in Figure 4A show the top-surface morphology of the as-deposited HPbI\textsubscript{3} film at low and high magnifications, respectively. The poor quality of the HPbI\textsubscript{3} film with only ∼50% coverage is clearly evident in Figure 4A. The underlying substrate is visible in Figure 4A inset corner. The atomic force microscope (AFM) image in Figure 4B confirms the rough surface, with a high root-mean-square (RMS) roughness of ∼180 nm. After CH\textsubscript{3}NH\textsubscript{2}-gas exposure for 2 s at room temperature followed by degassing for 2 s, the converted MAPbI\textsubscript{3} perovskite film appears remarkably uniform and full-coverage in the top-surface SEM images in Figure 4C. The AFM image in Figure 4D further demonstrates the uniform morphology and the smoothness (RMS roughness ∼6 nm) of the MAPbI\textsubscript{3} perovskite film over a 20 × 20 μm\textsuperscript{2} area. This confirms that the morphology of the resulting MAPbI\textsubscript{3} perovskite is nearly independent of the morphology of the nominally processed HPbI\textsubscript{3} solid precursor film, which is the direct result of the underlying transformative film-evolution mechanism illustrated in Figure 3.

PSCs were then fabricated using the MAPbI\textsubscript{3} perovskite thin films deposited using the method described above. Cross-sectional SEM image of a typical PSC (fractured) is shown in
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Figure S9A. The various layers are visible in that micrograph and are labeled as such: glass/FTO, c-TiO2, meso-TiO2/MAPbI3 perovskite, MAPbI3 perovskite (capping layer), hole-transporting material (HTM), and Ag top contact. The mesoporous TiO2 layer is tightly infiltrated with the fully converted phase-pure perovskite (Figure S8) forming a bicontinuous structure with a dense perovskite capping layer, as shown in Figure S9. Current density–voltage (J–V) responses in Figure 5B from the champion PSC (cell area 0.12 cm2) show a PCE of 14.5% (see Figure S13 for the MPP stabilized at one sun illumination (AM 1.5G, 100 mW·cm−2)). Since the typical J–V hysteresis is observed, stabilized PCE and J output at maximum power point (MPP) were measured over a period of 100 s under continuous forward and reverse scans, respectively, under one sun illumination (AM 1.5G, 100 mW·cm−2). The external quantum efficiency measurement (Figure S11) shows an integrated current density consistent with the Jsc. The PCE of small-area (0.12 cm2) PSCs shows a tight distribution (Table S1). Figure S12 shows J–V response for a large-area PSC (1.17 cm2) with a PCE of 14.5% (see Figure S13 for the MPP stabilized J and PCE output), which is close to the-state-of-the-art centimeter area PSCs,13 attesting to scalability of this MAPbI3 perovskite thin films deposition method based on the HPbI3–CH3NH3 precursor pair.

In closing, we have observed a strong room-temperature solid–gas interaction behavior between the HPbI3–CH3NH3 precursor pair, which shows promise for the deposition of high-quality MAPbI3 perovskite thin films for high-PCE PSCs. This strong precursor interaction results in ultrasmooth, full coverage MAPbI3 perovskite thin films, which is virtually independent of the poor morphology of the starting HPbI3 precursor films, making this deposition process highly robust. The chemical origins responsible for the transformative evolution of MAPbI3 perovskite thin films is elucidated. This study highlights the significance of precursor interaction chemistry in the formation of high-quality hybrid perovskite thin films, which is playing a central role in the scalable production of high-PCE PSCs of the future.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/jacs.5b11824.

Experimental details and data (PDF)

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Notes

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